



Docket: 14467.05

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

First Named Inventor:	John P. Snyder	
Appln. No.:	10/796,514	
Filing Date:	March 9, 2004	Examiner: Su C. Kim
Title:	TRANSISTOR HAVING HIGH DIELECTRIC CONSTANT GATE INSULATING LAYER AND SOURCE AND DRAIN FORMING SCHOTTKY CONTACT WITH SUBSTRATE	Group Art Unit: 2823

**AMENDMENT AND RESPONSE UNDER 37 C.F.R. 1.111**

Mail Stop Amendment  
Commissioner for Patents  
P. O. Box 1450  
Alexandria, Virginia 22313-1450

I hereby certify that this document is being sent via First Class U. S. mail addressed to: Mail Stop Amendment, Commissioner for Patents, P. O Box 1450, Alexandria, VA 22313-1450, on this 19 day of March, 2007.

Sue Hierabe  
(Signature)

Sir:

In response to the Office Action of September 19, 2006, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 15 of this paper.